

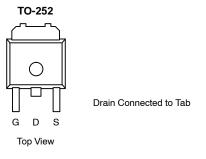
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$r_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A) <sup>a</sup>		
30	0.0043 @ V <sub>GS</sub> = 10 V	33		
	0.0065 @ V <sub>GS</sub> = 4.5 V	27		

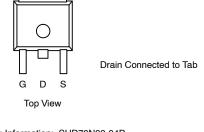
#### **FEATURES**

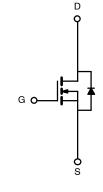
- TrenchFET® Power MOSFET
- 175°C Junction Temperature
- Optimized for Low-Side Synchronous Rectifier Operation
- 100% R<sub>g</sub> Tested

#### **APPLICATIONS**

- DC/DC Converters
- Synchronous Rectifiers







Ordering Information: SUD70N03-04P

N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	Limit	Unit		
Drain-Source Voltage		V <sub>DS</sub>	30	v		
Gate-Source Voltage		V <sub>GS</sub>	±20			
	T <sub>A</sub> = 25°C		33			
Continuous Drain Current <sup>a</sup>	T <sub>C</sub> = 25°C	- I <sub>D</sub>	70 <sup>b</sup>			
Pulsed Drain Current		I <sub>DM</sub>	100	_ A		
Continuous Source Current (Diode Conduction) <sup>a</sup>		Is	8.3 <sup>a</sup>	1		
	T <sub>C</sub> = 25°C	_	88			
Maximum Power Dissipation	T <sub>A</sub> = 25°C	P <sub>D</sub>	8.3 <sup>a</sup>	- w		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 175	°C		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
	t ≤ 10 sec	R <sub>thJA</sub>	15	18	°C/W	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		40	50		
Maximum Junction-to-Case		R <sub>thJC</sub>	1.2	1.5		

Surface Mounted on FR4 Board,  $t \le 10$  sec.

Limited by package.

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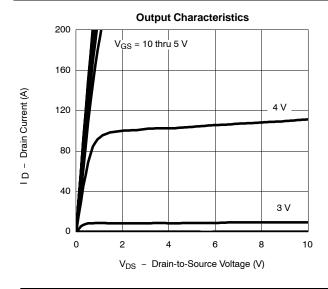


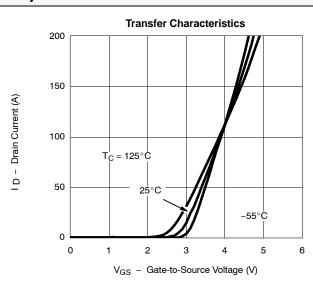
Parameter	Symbol	Test Condition	Min	Typ <sup>a</sup>	Max	Unit
Static	1			I		
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS}$ = 0 V, $I_D$ = 250 $\mu A$	30			·
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0		3.0	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA
7 0		V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V			1	μΑ
Zero Gate Voltage Drain Current	DSS	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125^{\circ}\text{C}$			50	
On-State Drain Current <sup>b</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	50			Α
		$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		0.0035	0.0043	
Drain-Source On-State Resistance <sup>b</sup>	r <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 20 A, T <sub>J</sub> = 125°C			0.007	Ω
	, ,	$V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$		0.0051	0.0065	
Forward Transconductanceb	9fs	$V_{DS} = 15 \text{ V}, I_{D} = 20 \text{ A}$	20			S
Dynamic <sup>a</sup>						
Input Capacitance	C <sub>iss</sub>			5100		
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		860		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			430		
Gate Resistance	R <sub>g</sub>	f = 1 MHz 0.5		1.0	1.5	Ω
Total Gate Charge <sup>c</sup>	Qg			90	135	nC
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS} = 15 \text{ V}, \ V_{GS} = 10 \text{ V}, \ I_{D} = 50 \text{ A}$		18		
Gate-Drain Charge <sup>c</sup>	$Q_{gd}$			16		
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			12	20	
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = 15 \text{ V}, R_L = 0.3 \Omega$		12	20	ns
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong 50 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 2.5 \Omega$		40	60	
Fall Time <sup>c</sup>	t <sub>f</sub>			10	15	
Source-Drain Diode Ratings ar	d Characteristic	c (T <sub>C</sub> = 25°C)	•			
Pulsed Current	I <sub>SM</sub>				100	Α
Diode Forward Voltage <sup>b</sup>	V <sub>SD</sub>	$I_F = 100 \text{ A}, V_{GS} = 0 \text{ V}$		1.2	1.5	V
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	$I_F = 50 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$	1	40	80	ns

#### Notes

- Guaranteed by design, not subject to production testing.
- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2%.
- a. Independent of operating temperature.

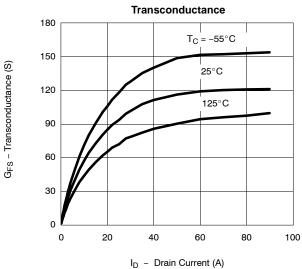
#### TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



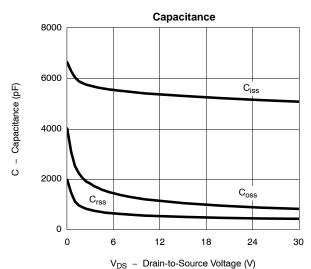




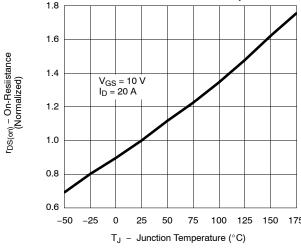
### TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)







On-Resistance vs. Junction Temperature



On-Resistance vs. Drain Current 0.010 0.008  $V_{GS} = 4.5 V$ 0.006 V<sub>GS</sub> = 10 V 0.004 0.002

20

R<sub>DS(on)</sub> – On-Resistance (Ω)

0.000

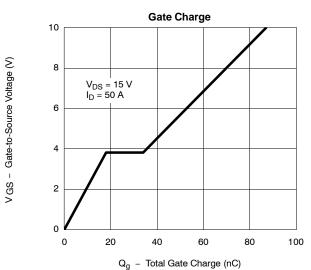
I<sub>D</sub> - Drain Current (A)

60

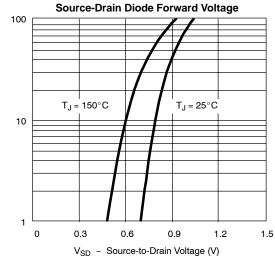
40

80

100

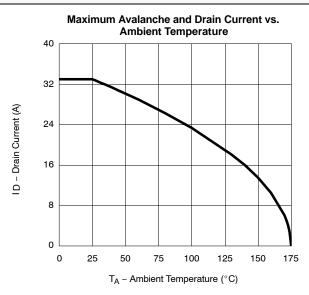


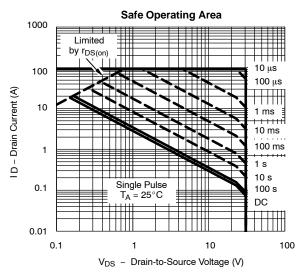


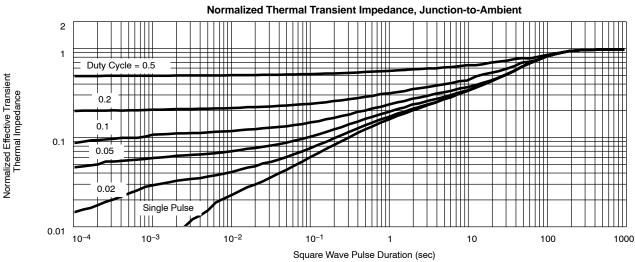


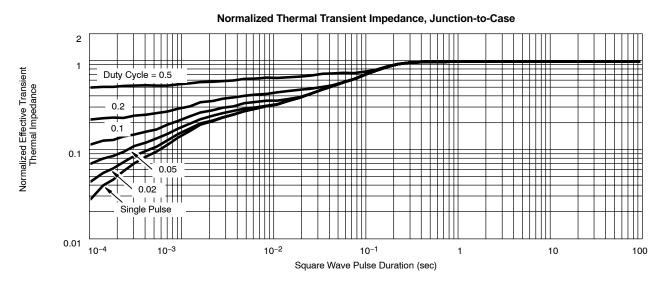


#### THERMAL RATINGS











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